

650 V, 40 A trench field-stop IGBT with full rated silicon diode

Rev. 1 — 28 June 2024

**Product data sheet** 

### **1. General Description**

The NGW40T65M3DFP is a robust Insulated-Gate Bipolar Transistor (IGBT) featuring third-generation technology. It combines carrier stored trench-gate and field-stop (FS) structures. The NGW40T65M3DFP is rated to 175 °C with optimized IGBT turn-off losses, and has a short-circuit withstand time of 5  $\mu$ s. This hard-switching 650 V, 40 A IGBT is optimized for high-voltage, high-frequency industrial power inverter applications and servo motor drive applications.

### 2. Features and benefits

- Collector current (I<sub>C</sub>) rated at 40 A
- Low conduction and switching losses
- · Stable and tight parameters for easy parallel operation
- Maximum junction temperature of 175 °C
- Fully rated as a soft fast reverse recovery diode
- 5 µs short circuit withstand time
- RoHS compliant, lead-free plating

### 3. Applications

- Motor drives for industrail and consumer appliances
  - Serve motors operating between 5-20 kW (up to 20 kHz) for robotics, elevators, operating grippers, in-line manufactuing, etc.
- Power inverters
  - Uninterruptible Power Supply (UPS) inverter
  - Photovoltaic (PV) strings
  - EV charging
- Induction heating
- Welding

### 4. Quick reference data

#### Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CE</sub>	collector-emitter voltage	T <sub>j</sub> = 25 °C	-	650	V
Tj	operating junction temperature		-40	+175	°C
t <sub>sc</sub>	short circuit withstand time	$V_{GE}$ = 15 ; $V_{CC}$ = 400 V; $T_j \le 150$ °C	-	5	μs



### 5. Pinning information

Table 2. Pinning information							
Pin	Symbol	Description	Simplified outline	Graphic symbol			
1	G	gate	mb				
2	С	collector		С			
3	E	emitter					
mb	С	mounting base; connected to collector		G			

## 6. Ordering information

#### Table 3. Ordering information

Type number	Package					
	Name	Description	Version			
NGW40T65M3DFP		Plastic single-ended through-hole package; heatsink mounted; 1 mounting hole; 3-lead TO-247-3L	<u>SOT429-2</u>			

# 7. Limiting values

#### Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
IGBT	,				
V <sub>CE</sub>	collector-emitter voltage	T <sub>j</sub> = 25 °C	-	650	V
I <sub>C</sub>	collector current	T <sub>case</sub> = 25 °C [1]	-	72	А
		T <sub>case</sub> = 100 °C [1]	-	48	А
I <sub>Cpuls</sub>	peak pulse collector current [2]		-	120	А
t <sub>sc</sub>	short circuit withstand time	V <sub>GE</sub> = 15 V; V <sub>CC</sub> = 400 V; T <sub>j</sub> ≤ 150 °C	-	5.0	μs
V <sub>GS</sub>	gate-source voltage		-20	+20	V
P <sub>tot</sub>	total power dissipation	T <sub>case</sub> = 25 °C	-	283	W
		T <sub>case</sub> = 100 °C	-	142	W
Tj	operating junction temperature		-40	+175	°C
T <sub>stg</sub>	storage temperature		-55	+150	°C
T <sub>solder</sub>	soldering temperature		-	260	°C
М	mounting torque, M3 screw		-	0.6	Nm
Diode					
l <sub>F</sub>	diode forward current	$T_{case} = 25 \ ^{\circ}C$ [1]	-	80	А
		T <sub>case</sub> = 100 °C [1]	-	49	А
I <sub>Fpuls</sub>	peak pulse diode current [2]		-	120	A

[1] Value limited by bondwire and  $T_{j(max)}$ .

[2]  $t_p$  limited by  $T_{j(max)}$ .

### 8. Thermal characteristics

Table 5. Thermal characteristics							
Symbol	Parameter	Conditions	Min	Тур	Мах	Unit	
R <sub>th(j-c)</sub>	thermal resistance from junction to case	IGBT	-	0.45	0.53	K/W	
		diode	-	0.71	0.84	K/W	
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	-	-	40	K/W	

### 9. Characteristics

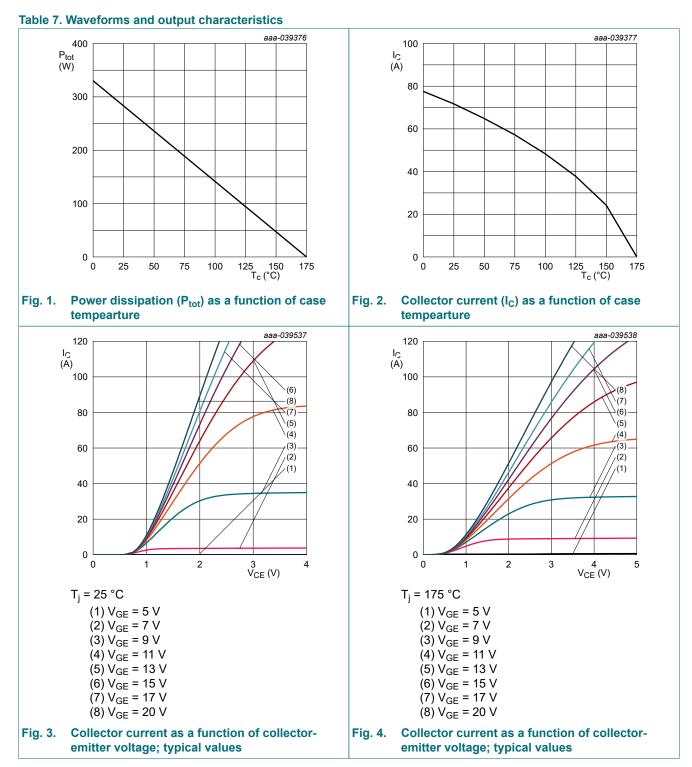
#### **Table 6. Characteristics**

All values at  $T_i = 25$  °C, unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static ch	aracteristics	· · · · · · · · · · · · · · · · · · ·				
V <sub>(BR)CE</sub>	collector-emitter breakdown voltage	V <sub>GE</sub> = 0 V; I <sub>C</sub> = 0.2 mA	650	-	-	V
V <sub>CEsat</sub>	collector-emitter saturation	V <sub>GE</sub> = 15 V; I <sub>C</sub> = 40 A; T <sub>j</sub> = 25 °C	-	1.5	1.9	V
	voltage	V <sub>GE</sub> = 15 V; I <sub>C</sub> = 40 A; T <sub>j</sub> = 175 °C	-	1.9	-	V
V <sub>F</sub>	diode forward voltage	V <sub>GE</sub> = 0 V; I <sub>F</sub> = 40 A; T <sub>j</sub> = 25 °C	-	1.62	2.1	V
		V <sub>GE</sub> = 0 V; I <sub>F</sub> = 40 A; T <sub>j</sub> = 175 °C	-	1.33	-	V
V <sub>GE(th)</sub>	gate-emitter threshold voltage	I <sub>C</sub> = 0.4 mA; V <sub>CE</sub> = V <sub>GE</sub> ; T <sub>j</sub> = 25 °C	4.3	5	5.7	V
I <sub>CES</sub>	zero gate voltage collector	V <sub>CE</sub> = 650 V; V <sub>GE</sub> = 0 V; T <sub>j</sub> = 25 °C	-	10	-	nA
	current	V <sub>CE</sub> = 650 V; V <sub>GE</sub> = 0 V; T <sub>j</sub> = 175 °C	-	0.5	-	mA
I <sub>GES</sub>	gate-emitter leakage current	V <sub>CE</sub> = 0 V; V <sub>GE</sub> = 20 V	-	-	100	nA
g <sub>fs</sub>	transconductance	V <sub>CE</sub> = 20 V; I <sub>C</sub> = 40 A; T <sub>j</sub> = 25 °C	-	20	-	S
r <sub>G</sub>	integrated gate resistor		-	1.3	-	Ω
Dynamic	characteristics					
Cies	input capacitance	V <sub>CE</sub> = 25 V; V <sub>GE</sub> = 0 V; f = 1 MHz	-	2040	-	pF
C <sub>oes</sub>	output capacitance		-	136	-	pF
C <sub>res</sub>	reverse transfer capacitance		-	31	-	pF
Q <sub>G</sub>	gate charge	V <sub>CC</sub> = 520 V; V <sub>GE</sub> = 15 V; I <sub>C</sub> = 40 A	-	130	-	nC
L <sub>sCE</sub>	internal stray inductance	measured 5 mm from case	-	7.9	-	nH
I <sub>C(sc)</sub>	short circuit collector current	$V_{GE}$ = 15 V; $V_{CC}$ = 400 V; $t_{sc} \le 5 \ \mu s$ ; $T_j \le 150$ ° C	-	130	-	A

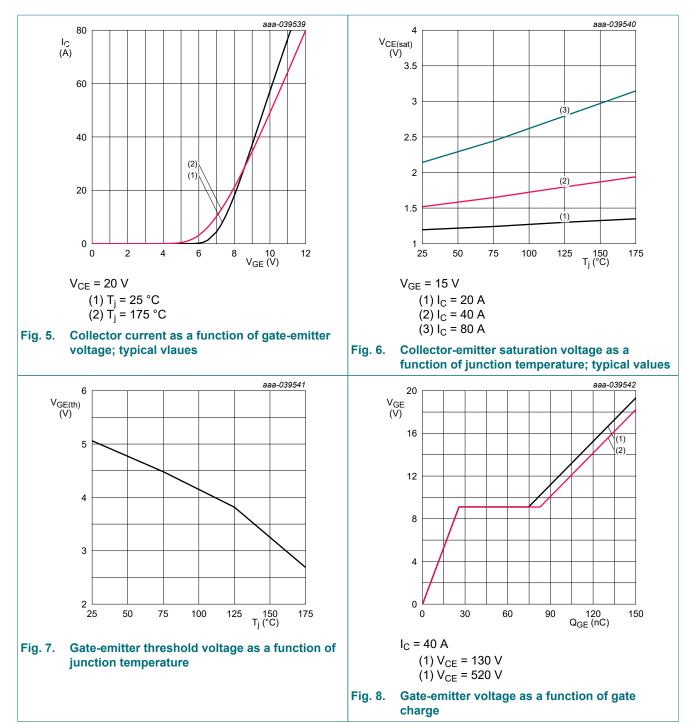
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
IGBT sw	vitching characteristics, indu	ctive load		1			
t <sub>d(on)</sub>	turn-on delay time	V <sub>GE</sub> = 15/0 V;	T <sub>j</sub> = 25 °C	-	22	-	ns
		$V_{CC}$ = 400 V; I <sub>C</sub> = 40 A; r <sub>G(on)</sub> = 10 Ω; r <sub>G(off)</sub> = 10 Ω;	T <sub>j</sub> = 175 °C	-	20	-	ns
t <sub>r</sub>	rise time	see Fig. 27 and Fig. 28	T <sub>j</sub> = 25 °C	-	22	-	ns
			T <sub>j</sub> = 175 °C	-	23	-	ns
t <sub>d(off)</sub>	turn-off delay time		T <sub>j</sub> = 25 °C	-	185	-	ns
			T <sub>j</sub> = 175 °C	-	220	-	ns
t <sub>f</sub>	fall time	-	T <sub>j</sub> = 25 °C	-	13	-	ns
			T <sub>j</sub> = 175 °C	-	50	-	ns
Eon	turn-on switching loss		T <sub>j</sub> = 25 °C	-	1.05	-	mJ
			T <sub>j</sub> = 175 °C	-	2.15	-	mJ
E <sub>off</sub>	turn-off switching loss		T <sub>j</sub> = 25 °C	-	0.52	-	mJ
			T <sub>j</sub> = 175 °C	-	0.9	-	mJ
E <sub>ts</sub>	total switching loss		T <sub>j</sub> = 25 °C	-	1.57	-	mJ
			T <sub>j</sub> = 175 °C	-	3.05	-	mJ
Diode sv	witching characteristics, indu	ictive load					
t <sub>rr</sub>	diode reverse recovery time	V <sub>R</sub> = 400 V; I <sub>F</sub> = 40 A;	T <sub>j</sub> = 25 °C	-	55	-	ns
		ΔI <sub>F</sub> /Δt = 1000 A/μs; see <u>Fig. 26</u>	T <sub>j</sub> = 175 °C	-	215	-	ns
Q <sub>rr</sub>	diode reverse recovery	366 <u>1 lg. 20</u>	T <sub>j</sub> = 25 °C	-	700	-	nC
	charge		T <sub>j</sub> = 175 °C	-	3830	-	nC
l <sub>rrm</sub>	diode peak reverse recovery		T <sub>j</sub> = 25 °C	-	22	-	А
	current		T <sub>j</sub> = 175 °C	-	37	-	Α
E <sub>rr</sub>	reverse recovery energy		T <sub>j</sub> = 25 °C	-	0.12	-	mJ
			T <sub>j</sub> = 175 °C	-	0.36	-	mJ
di <sub>rr</sub> /dt	diode peak rate or fall of		T <sub>j</sub> = 25 °C	-	650	-	A/µs
	reverse recovery current		T <sub>j</sub> = 175 °C	-	760	-	A/µs

### 650 V, 40 A trench field-stop IGBT with full rated silicon diode

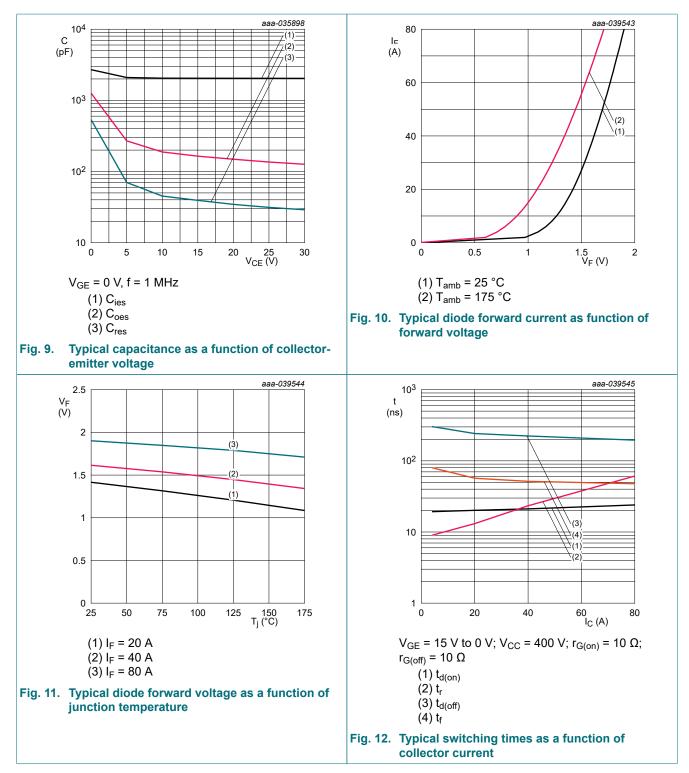


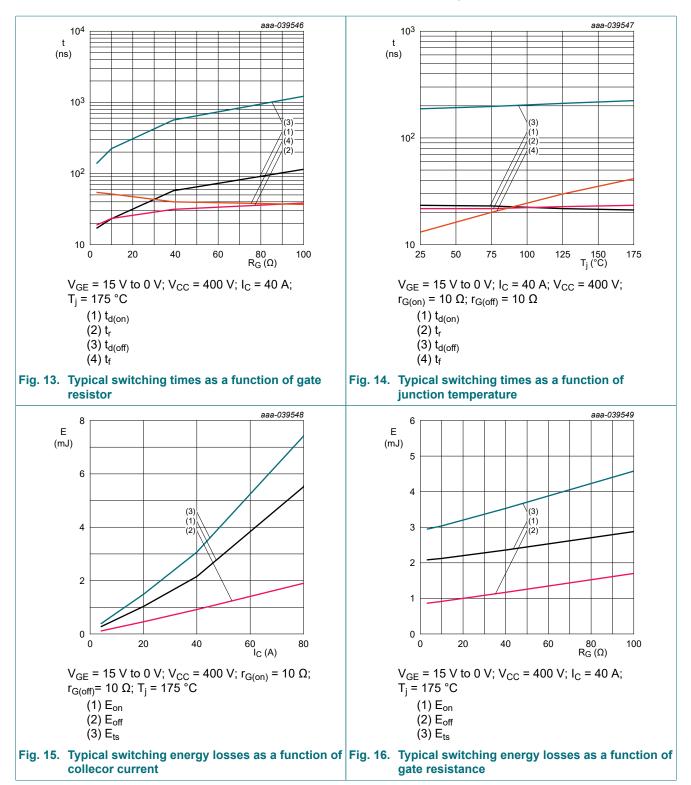
### 9.1. Waveforms and output characteristics

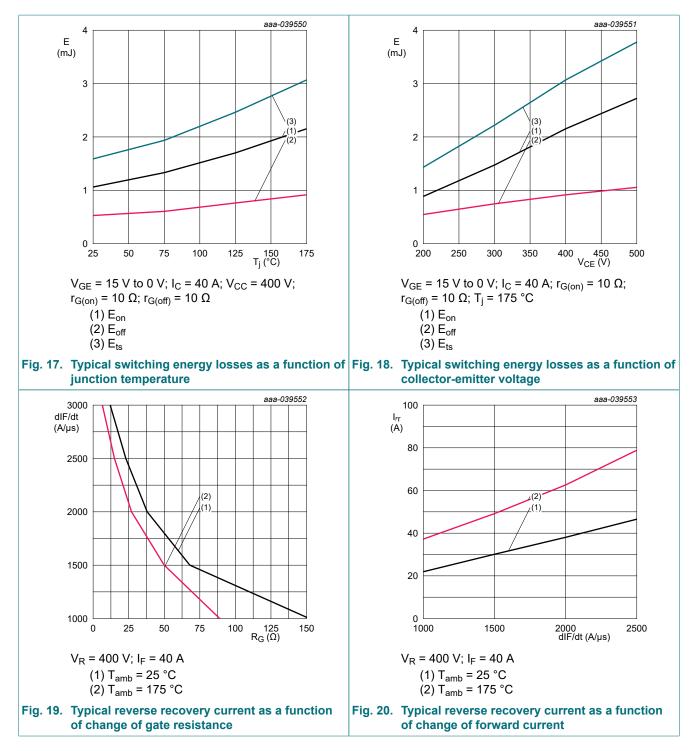
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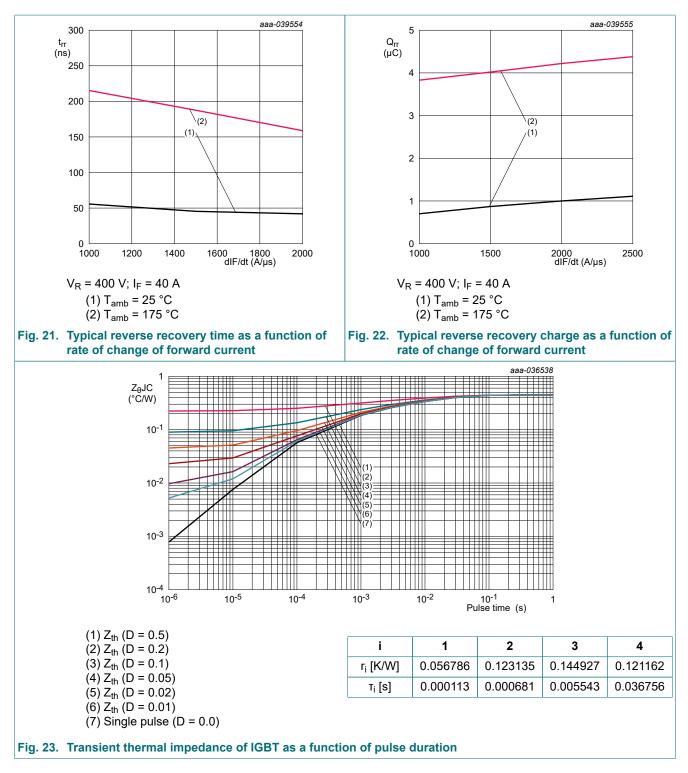


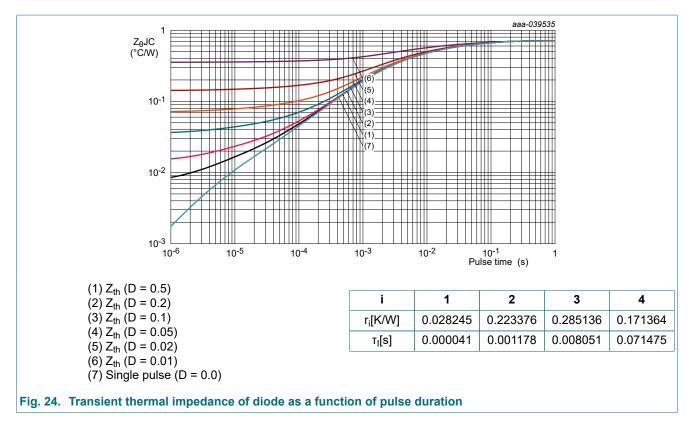
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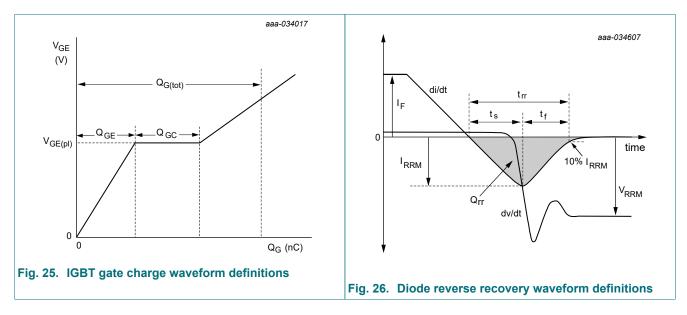




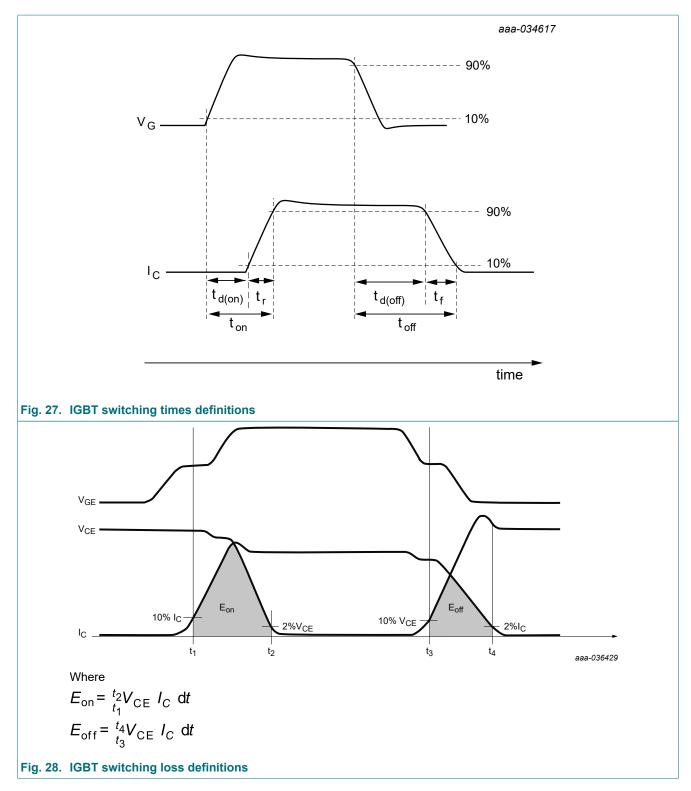




9.2. Waveforms



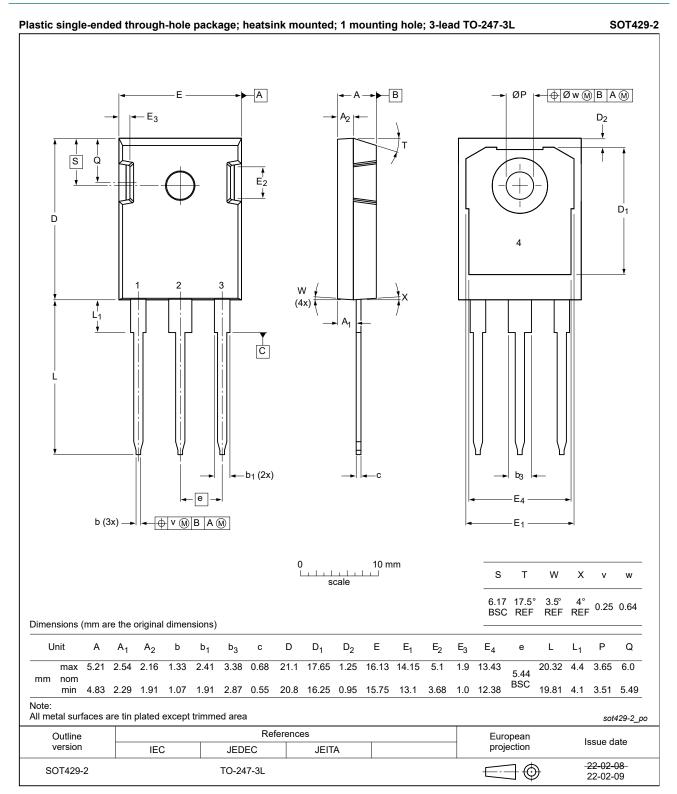
#### 650 V, 40 A trench field-stop IGBT with full rated silicon diode



NGW40T65M3DFP

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### 10. Package outline



# **11. Revision history**

Table 8. Revision history						
Document ID	Release date	Data sheet status	Change notice	Supersedes		
NGW40T65M3DFP v. 1	20240628	Product data sheet	-	-		

### 12. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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